Professor N. Kato, Ordinary Members – Professor S. Amelinckx, Professor Th. Hahn, Professor M. Nardelli, Professor H. Neels, Dr V. I. Simonov, Professor M. M. Woolfson.

Dr S. C. Abrahams was reappointed Editor of Acta Crystallographica and Chairman of the Commission on Journals, Professor M. Hart was reappointed Editor of the Journal of Applied Crystallography and Co-Chairman of the Commission on Journals. Professor M. Nardelli and Professor R. Norrestam were appointed as Co-Editors of Acta Crystallographica and Professor G. Allegra and Dr S. Jagner have retired. Professor G. Ferguson was appointed as Editor of Structure Reports, succeeding Professor J. Trotter who has retired as Editor of this publication. Professor M. G. Rossman was elected Chairman of the new Commission on Biological-Macromolecule Crystallography, Dr M. J. Cooper was elected Chairman of the Commission on Charge, Spin and Momentum Densities, Dr E. Kaldis was re-elected Chairman of the Commission on Crystal Growth and Characterization of Materials (formerly the Commission on Crystal Growth), Professor S. Abrahamsson was reelected Chairman of the Commission on Crystallographic Apparatus, Dr S. R. Hall was elected Chairman of the Commission on Crystallographic Computing, Dr I. D. Brown was elected Chairman of the Commission on Crystallographic Data, Dr S. C. Abrahams continues as Chairman of the Commission on Crystallographic Nomenclature as a result of his reappointment as Chairman of the Commission on Journals, Dr B. Buras was elected Chairman of the Commission on Crystallographic Studies at Controlled Pressures and Temperatures, Professor P. Krishna was elected Chairman of the Commission on Crystallographic Teaching, Dr P. Goodman was elected Chairman of the Commission on Electron Diffraction and Dr M. S. Lehmann was elected Chairman of the Commission on Neutron Diffraction.

The full membership of the Commissions of the Union, and the Union representatives on other bodies, will be given in the Report of the Twelfth General Assembly and International Congress of Crystallography, which will be published in Section A of Acta Crystallographica in due course.

Professor **P. P. Ewald** was unable to attend the Twelfth International Congress of Crystallography but sent the following message: "Feeling too old for joining in the celebrations of the XII Congress, I still

remain interested in the success of this International Congress of Crystallography. May its dealings not only show the advances in the understanding of the material properties of condensed matter but, beyond this, show how only through world-wide peaceful cooperation a thorough understanding can be gained. I wish you good results for your deliberations".

Professor **E. F. Bertaut**, Director of the Laboratoire de Cristallographie, Centre de Tri, Grenoble has received the degree of Doctor of Philosophy *Honoris Causae* from the Johann Wolfgang Goethe University, Frankfurt.

Professor **T. L. Blundell,** Birkbeck College, London has been appointed Director of the International School of Crystallography at the Ettore Majorana Centre for Scientific Culture at Erice, Sicily.

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World Directory of Crystallographers Sixth Edition

The Sixth Edition of the World Directory of Crystallographers and of Other Scientists Employing Crystallographic Methods, General Editor A. L. Bednowitz, has just been published on behalf of the International Union of Crystallography by D. Reidel Publishing Company, PO Box 17, 3300 AA Dordrecht, The Netherlands and 160 Old Derby Street, Hingham, MA 02043, USA, from whom copies may be ordered direct at a price of US \$10 (25 Netherlands Guilders) post free. It contains short biographical data on over 8100 scientists from 68 countries. The biographical data include full name and title, address, year of birth, highest degree, field of study, university and year of highest degree, present position, telephone number and major scientific interests. There is also a comprehensive name index.

For those crystallographers whose names have not been included in the Sixth Edition and for any whose entries contain errors, Data Entry forms for the Seventh Edition are available from Dr Allan L. Bednowitz, General Editor, IUCr World

Directory of Crystallographers, c/o IBM T. J. Watson Research Center, PO Box 218, Yorktown Heights, NY 10598, USA.

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Delays in Publication

Median publication time for full articles in Acta Crystallographica and Journal of Applied Crystallography (JAC), based on the elapsed time between final acceptance of manuscripts and their nominal date of publication, has been close to five months in Section A and JAC and four months in Section B in recent years. Short communications and short structural papers have experienced slightly shorter median publication times. It is deeply regretted that publication times will increase later this year to about eight months on average as a consequence of the reduced number of pages that can be published in 1981 without incurring an unsustainable loss, as large and unfavourable movements in international exchange rates have resulted in a substantial deficit in the publication of Volume 36 of Acta Crystallographica and have already nullified the effect of the increase in subscription rates for Volume 37. Various alternative procedures for the production of the journals are being investigated with the aim of reducing costs and reducing the effect of variations in exchange rates, and every effort will be made to return to normal publication schedules with least delay.

Book Reviews

Works intended for notice in this column should be sent direct to the Book-Review Editor (J. H. Robertson, School of Chemistry, University of Leeds, Leeds LS2 9JT, England). As far as practicable books will be reviewed in a country different from that of publication.

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Crystals: growth, properties and applications, Vol. 3. Edited by H. C. Freyhardt. Pp. iv+163. Berlin, Heidelberg, New York: Springer-Verlag, 1980. Price DM 72.80, US \$ 43.00.

The current importance of III-V compounds for the development of advanced semiconductor devices makes this third